

Fig. 1

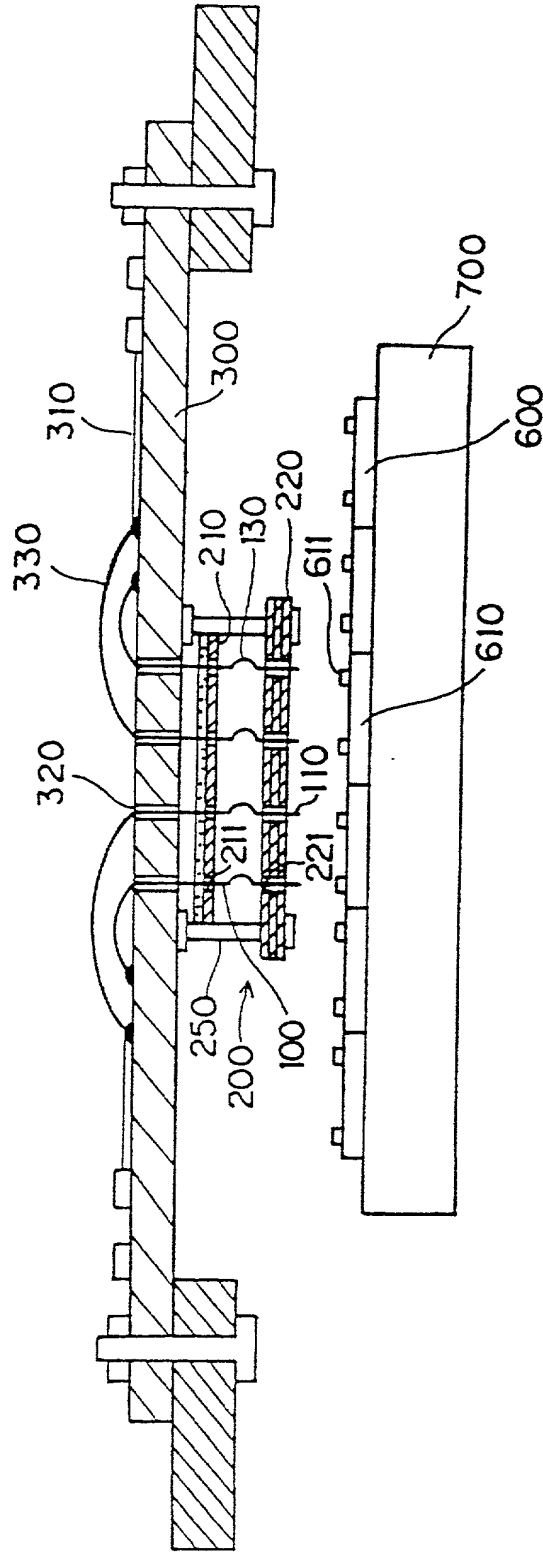


Fig. 2

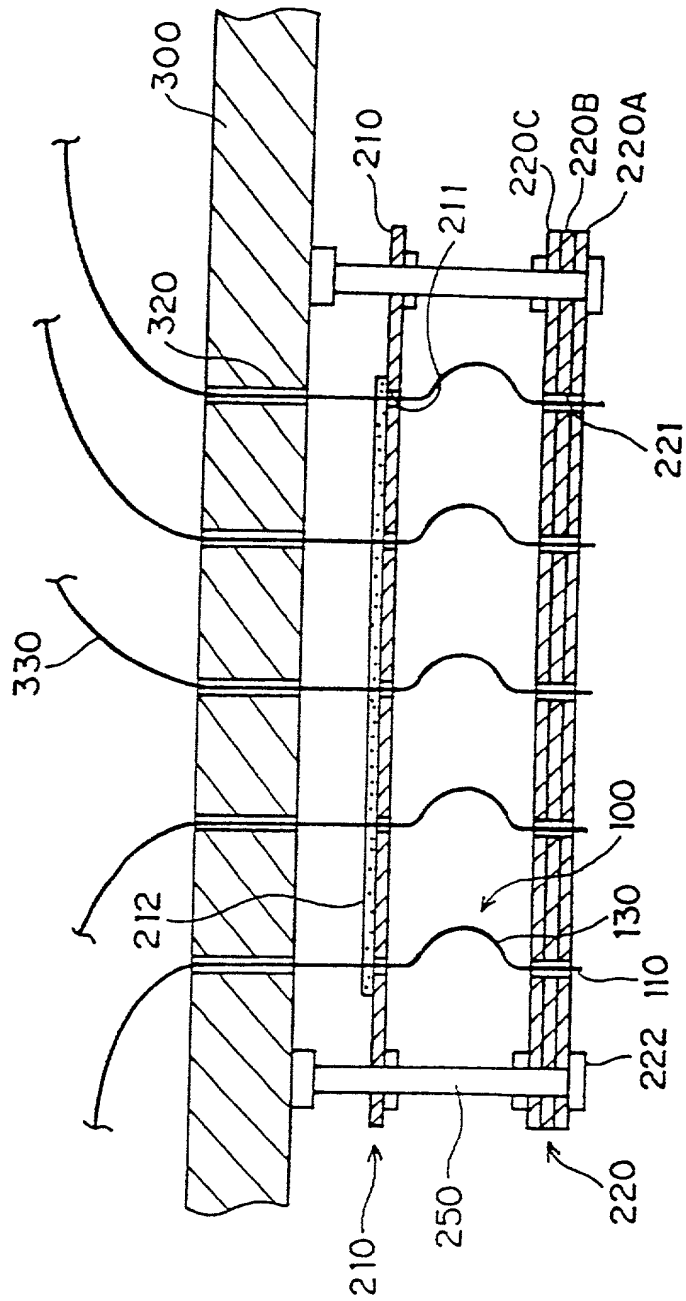


Fig. 3

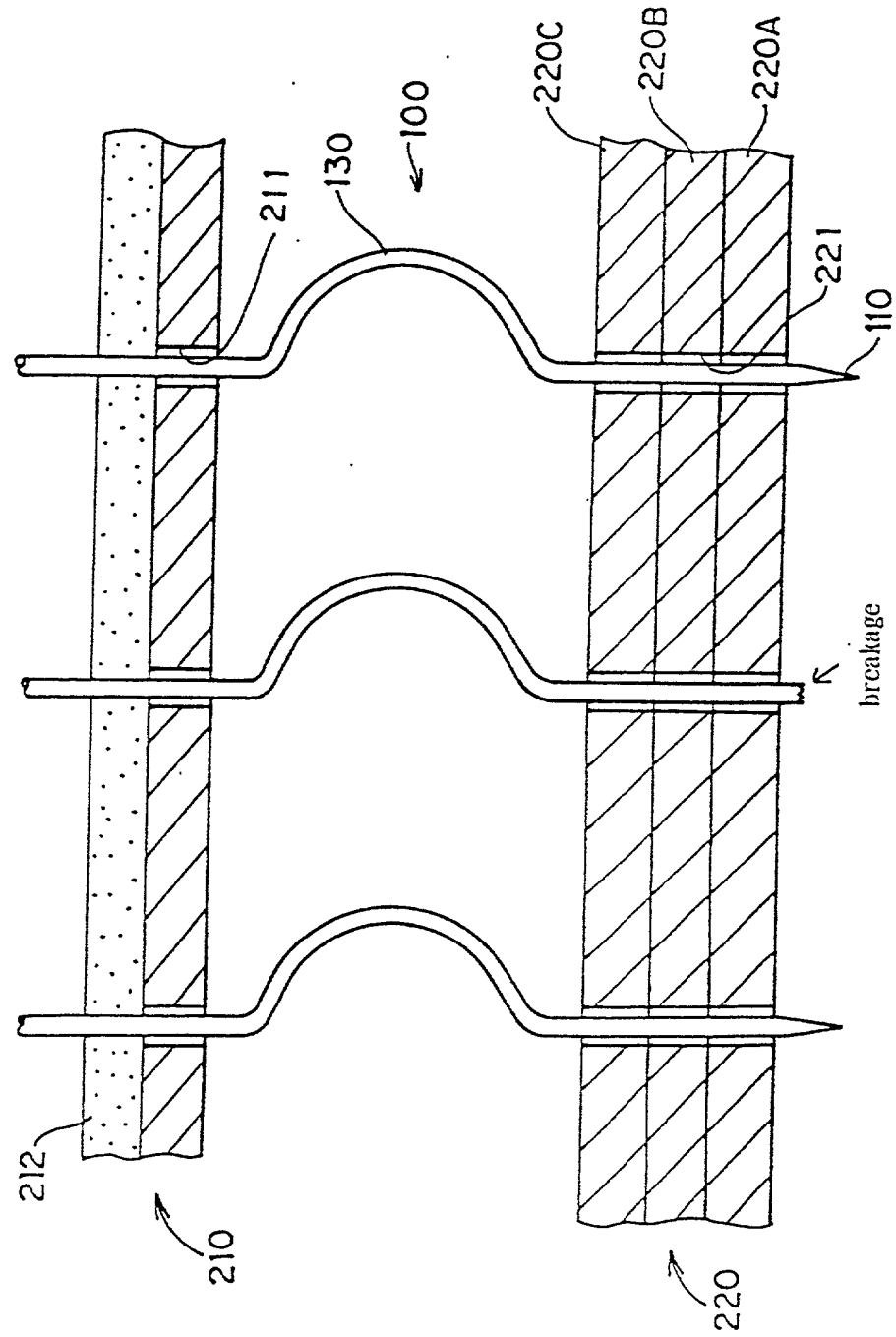


FIG. 4 is a cross-sectional view of a device 100, showing a substrate 110 with a central layer 130 and side layers 210 and 220. The device includes a central channel 130 and side channels 210 and 220. The side layers 210 and 220 are shown with different hatching patterns. The central layer 130 is shown with a wavy profile. The device is shown in a cross-sectional view, with the central channel 130 and side channels 210 and 220. The side layers 210 and 220 are shown with different hatching patterns. The central layer 130 is shown with a wavy profile. The device is shown in a cross-sectional view, with the central channel 130 and side channels 210 and 220.

Fig. 4

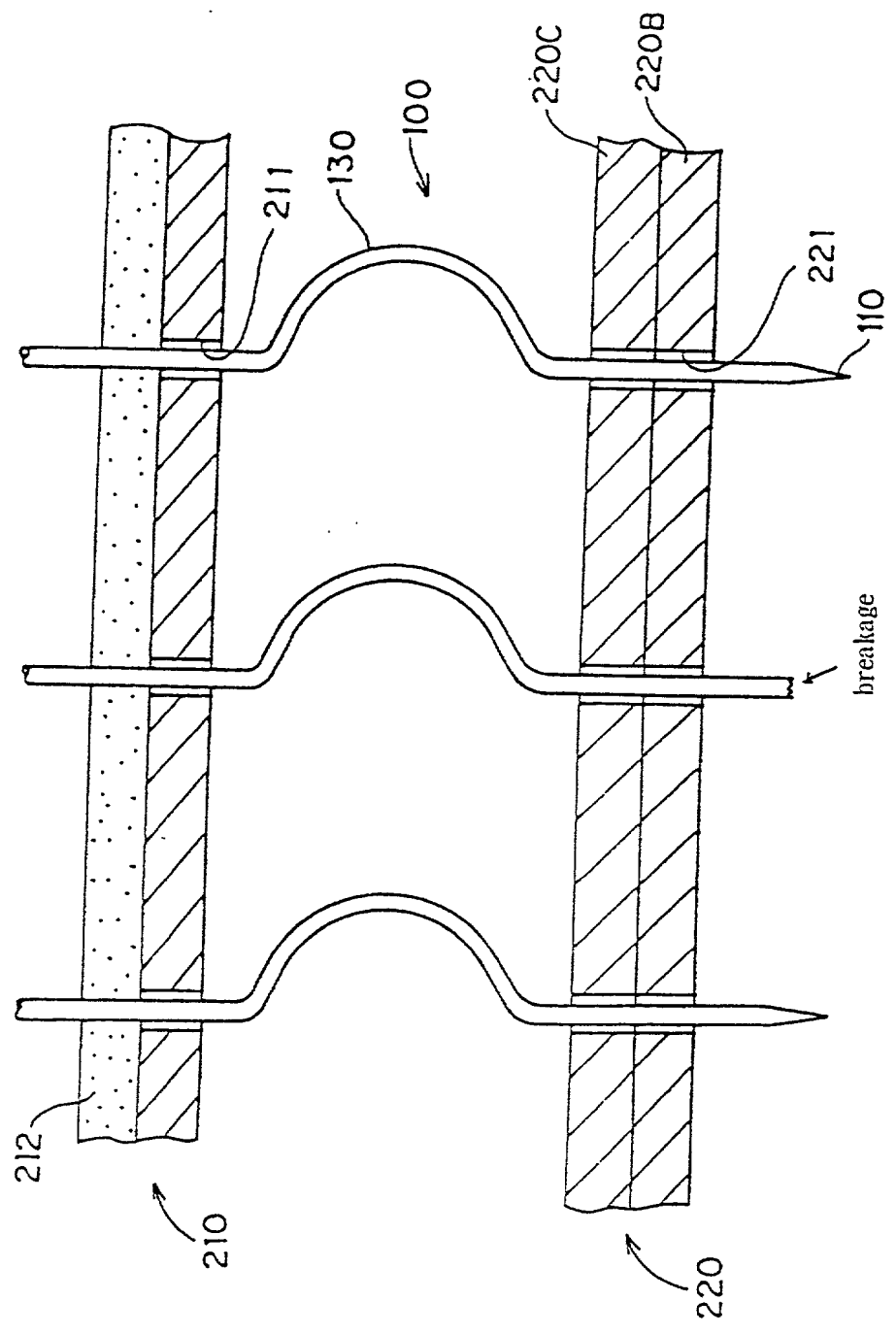


Fig. 5

